

## Features

- Low operating voltage:  $\pm 12\text{V}$
- Ultra low capacitance: 7pF typical
- Ultra low leakage: nA level
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
  - – IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30\text{kV}$
    - Contact discharge:  $\pm 30\text{kV}$
  - – IEC61000-4-5 (Lightning) 8A (8/20 $\mu\text{s}$ )
- RoHS Compliant

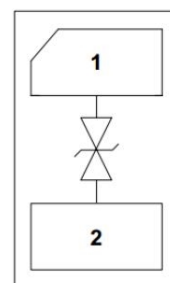
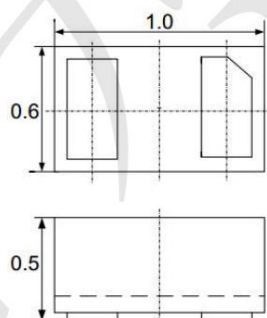
## Mechanical Characteristics

- Package: DFN1006-2 (1.0 $\times$ 0.6 $\times$ 0.5mm)
- Lead Finish: NiPdAu
- Case Material: “Green” Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Shipping Qty : 10000/7Inch Tape & Reel

## Applications

- Cellular Handsets & Accessories
- Personal Digital Assistants
- Display Port
- MDDI Ports
- Audio Players
- PCI Express
- Serial ATA

## Dimensions and Pin Configuration



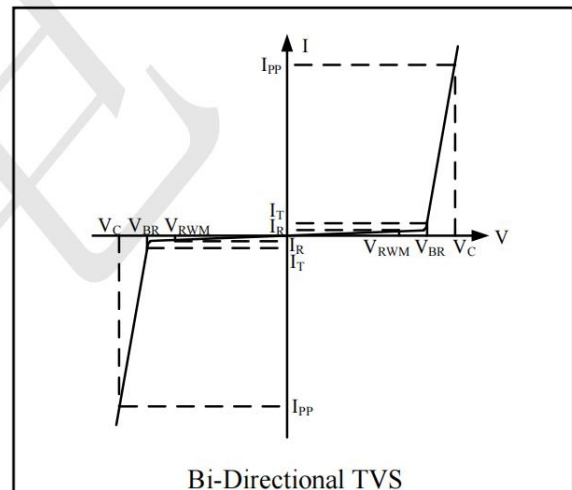
**Marking: MW**

**Absolute Maximum Ratings** (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P <sub>PK</sub>	150	W
Peak Pulse Current (8/20μs)	I <sub>PP</sub>	8	A
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	T <sub>J</sub>	-55 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

**Electrical Characteristics** (TA=25°C unless otherwise specified)

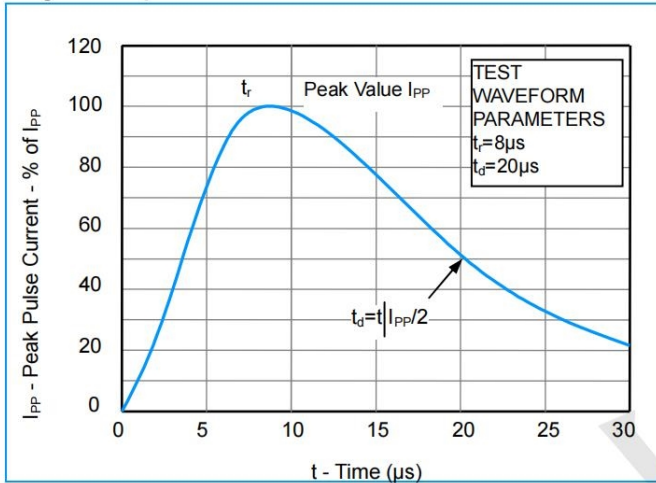
Symbol	Parameter
V <sub>RWM</sub>	Nominal Reverse Working Voltage
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Reverse Breakdown Voltage @ I <sub>T</sub>
I <sub>T</sub>	Test Current for Reverse Breakdown
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
I <sub>PP</sub>	Maximum Peak Pulse Current
C <sub>ESD</sub>	Parasitic Capacitance
V <sub>R</sub>	Reverse Voltage
f	Small Signal Frequency



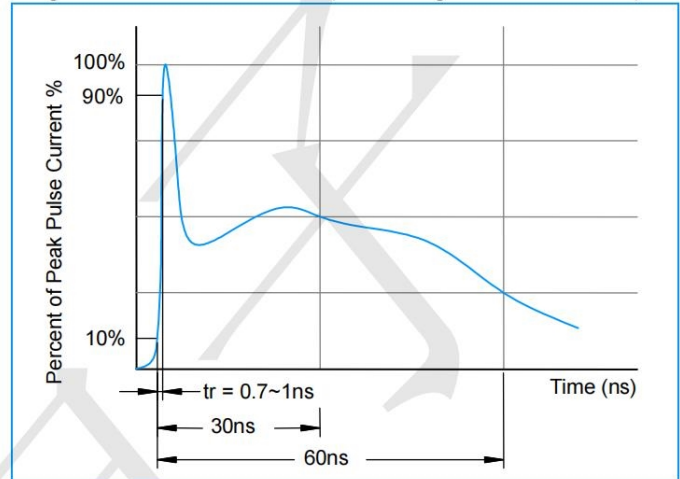
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>			12	V	
Breakdown Voltage	V <sub>BR</sub>	13.7			V	I <sub>T</sub> = 1mA
Reverse Leakage Current	I <sub>R</sub>			100	nA	V <sub>RWM</sub> = 12V
Clamping Voltage	V <sub>C</sub>			12	V	I <sub>PP</sub> = 8A (8 x 20μs pulse)
Junction Capacitance	C <sub>J</sub>		7	10	pF	V <sub>R</sub> = 0V, f = 1MHz

## Characteristic Curves

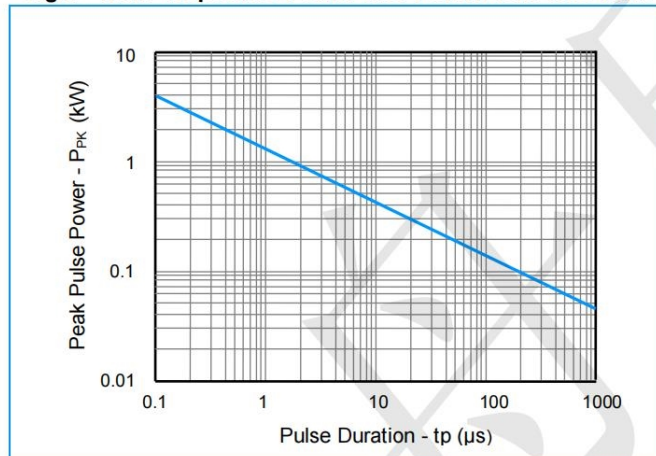
**Fig1. 8/20 $\mu$ s Pulse Waveform**



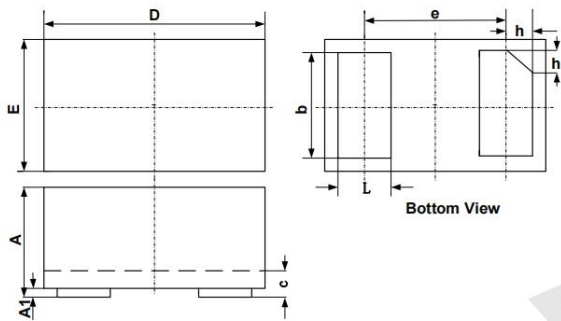
**Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)**



**Fig3. Non - Repetitive Peak Pulse Power vs. Pulse Time**

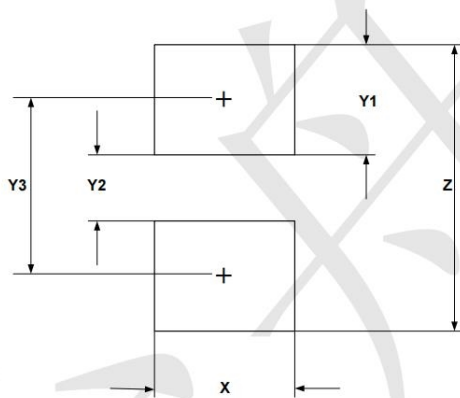


**Outline Drawing - DFN1006-2**



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

**Land Pattern - DFN1006-2**



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052